

Platin FRED tentative

Туре	Ag [*] Al [*]	V_{RRM} [∀]	<i>I_F</i> [A]	Chip Size [mm] x [mm]	Package	<u> </u>
DMLP 130		300	300	13.00 9.77	sawn on foil ✓ unsawn wafer ✓* in waffle pack ✓	
	*Frontside options				*Please contact IXYS chip sales	

Mechanical Parameters

Area active 105.86 mm² Area total 127.01 mm² Wafer size Ø 150 mm μm **Thickness** 250 Si Material Max. possible chips per wafer 109 Passivation front side Polyimide Metallization top side bondable: ΑI solderable (only): Al / Ti / Ni / Ag* Metallization backside Recom. wire bonds (AI) Anode Number 20 Ø 380 µm Reject Ink Dot Size Ø 0.4-1.0 mm Recom. Storage Environment in org. container, in dry nitrogen < 6 month sawn on foil in org. container, in dry nitrogen < 2 year unsawn wafer in org. container, in dry nitrogen < 2 year in waffle pack -40 ... 40 °C *Sinterable top/bottom side on request

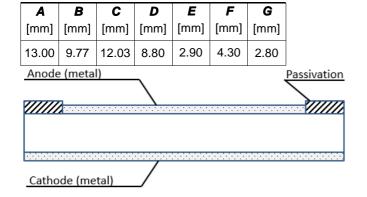
Features:

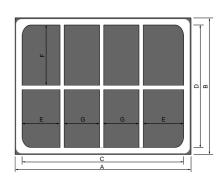
- Polyimide passivated
- Anode top
- ●Epitaxial diode
- Pt doped

Applications

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders
- PDP

Dimensions







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Electrica	al parameters				4.1
Symbol	Conditions		Ratings		
		min.	typ.	max.	
I _R	$V = V_R = V_{RRM} T_{VJ} = 25^{\circ}C$			100	μΑ
	T _{VJ} =150 °C		, <	1000	μΑ
V _F	$I_F = 300 \text{ A}$ $T_{VJ} = 25^{\circ}\text{C}$		40	1.10	V
	T _{VJ} = 150°C			0.85	V
V _{F0}	For power-loss calculations only			0.66	V
r _F	T _{vJ} 175°C			0.5	$ m \Omega $
T _{VJ}		-40		175	°C
I _{F(AV)} *	$T_c = 125 ^{\circ}\text{C}$ 180° rect. $T_{VJ} = 175 ^{\circ}\text{C}$	X/ A			Α
I _{FSM} *	$T_{yy} = 45^{\circ}\text{C}$ $t = 10 \text{ ms } (50 \text{ Hz}), \text{ sine}$	/X/		1650	Α
	$V_{R} = 0 V$ $t = 8.3 \text{ ms } (60 \text{ Hz}), \text{ sine}$				Α
	$T_{VJ} = 175 \text{ °C}$ $t = 10 \text{ ms } (50 \text{ Hz}), \text{ sine}$				Α
	$V_R = 0 V$ $t = 8.3 \text{ ms } (60 \text{ Hz}), \text{ sine}$				Α
ft *	$T_{VJ} = 45^{\circ}C$ $t = 10$ ms (50 Hz), sine			13610	A^2s
	$V_R = 0 V$ $t = 8.3 \text{ ms } (60 \text{ Hz}), \text{ sine}$			tbd	A s
	$T_{VJ} = 175 ^{\circ}\text{C}$ $t = 10 \text{ms} (50 \text{Hz}), \text{ sine}$			tbd	A 2s
	$V_{R} = 0 V$ $t = 8.3 \text{ ms } (60 \text{ Hz}), \text{ sine}$			tbd	A 2s
E _{AS} *	$I_{AS} = 9 \text{ A}$; L = 100 μH ; $T_{VJ} = 25^{\circ}\text{C}$; non repetitive			tbd	mJ
I _{AR} *	$V_A = 1.5 \cdot V_{RRM}$ typ.; f = 10 kHz; repetitive			tbd	А
R _{thJC} *	DC current			0.16	K/W
t,,	$V_R = 100 \text{ V}$; I _F 200 A; -di _E /dt 200 A/µs $T_{VJ} = 25^{\circ}\text{C}$		85		ns
I _{RM}	$V_R = 100 \text{ V}; I_F = 200 \text{ A}; -\text{di}_F/\text{dt} 200 \text{ A/µs} T_{VJ} = 25^{\circ}\text{C}$		6.5		Α

^{*} Data according to assembled Chip

Data according to IEC 60747

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- to establish joint measures to ensure application specific product capabilities and notify that IXYS may delivery dependent on the realization of any such measures.